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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	1000
Number of Logic Elements/Cells	8000
Total RAM Bits	226304
Number of I/O	86
Number of Gates	
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	132-LFBGA, CSPBGA
Supplier Device Package	132-CSBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lfxp2-8e-5m132i

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Introduction

LatticeXP2 devices combine a Look-up Table (LUT) based FPGA fabric with non-volatile Flash cells in an architecture referred to as flexiFLASH.

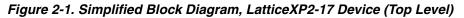
The flexiFLASH approach provides benefits including instant-on, infinite reconfigurability, on chip storage with FlashBAK embedded block memory and Serial TAG memory and design security. The parts also support Live Update technology with TransFR, 128-bit AES Encryption and Dual-boot technologies.

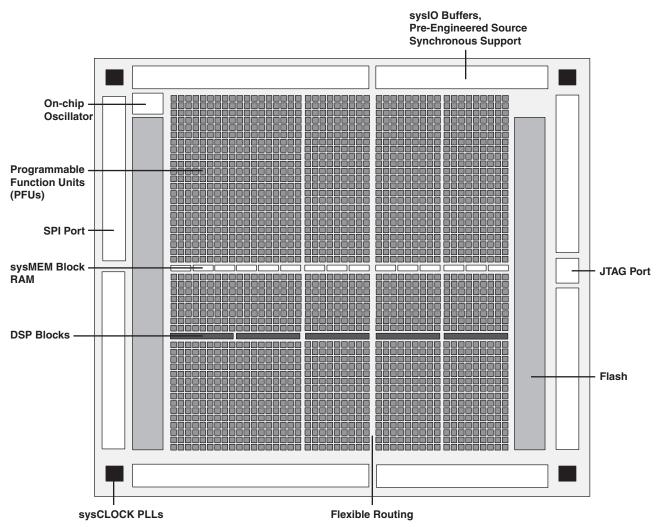
The LatticeXP2 FPGA fabric was optimized for the new technology from the outset with high performance and low cost in mind. LatticeXP2 devices include LUT-based logic, distributed and embedded memory, Phase Locked Loops (PLLs), pre-engineered source synchronous I/O support and enhanced sysDSP blocks.

Lattice Diamond[®] design software allows large and complex designs to be efficiently implemented using the LatticeXP2 family of FPGA devices. Synthesis library support for LatticeXP2 is available for popular logic synthesis tools. The Diamond software uses the synthesis tool output along with the constraints from its floor planning tools to place and route the design in the LatticeXP2 device. The Diamond tool extracts the timing from the routing and back-annotates it into the design for timing verification.

Lattice provides many pre-designed Intellectual Property (IP) LatticeCORE[™] modules for the LatticeXP2 family. By using these IPs as standardized blocks, designers are free to concentrate on the unique aspects of their design, increasing their productivity.







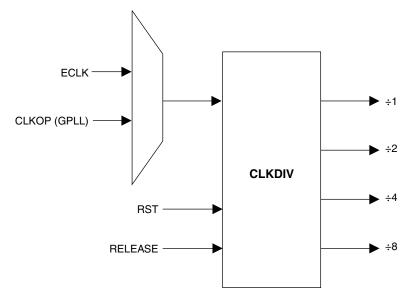
PFU Blocks

The core of the LatticeXP2 device is made up of logic blocks in two forms, PFUs and PFFs. PFUs can be programmed to perform logic, arithmetic, distributed RAM and distributed ROM functions. PFF blocks can be programmed to perform logic, arithmetic and ROM functions. Except where necessary, the remainder of this data sheet will use the term PFU to refer to both PFU and PFF blocks.

Each PFU block consists of four interconnected slices, numbered Slice 0 through Slice 3, as shown in Figure 2-2. All the interconnections to and from PFU blocks are from routing. There are 50 inputs and 23 outputs associated with each PFU block.



Figure 2-5. Clock Divider Connections



Clock Distribution Network

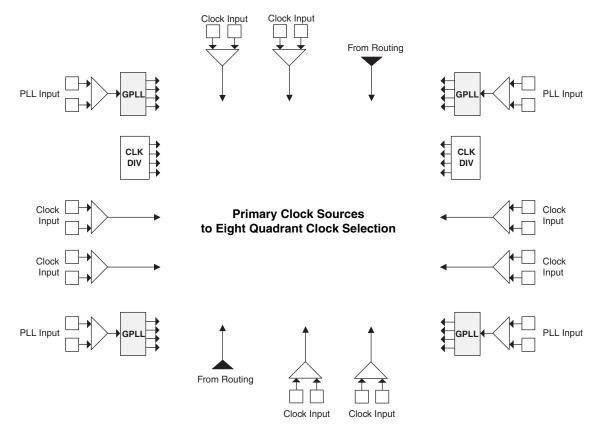
LatticeXP2 devices have eight quadrant-based primary clocks and between six and eight flexible region-based secondary clocks/control signals. Two high performance edge clocks are available on each edge of the device to support high speed interfaces. The clock inputs are selected from external I/Os, the sysCLOCK PLLs, or routing. Clock inputs are fed throughout the chip via the primary, secondary and edge clock networks.

Primary Clock Sources

LatticeXP2 devices derive primary clocks from four sources: PLL outputs, CLKDIV outputs, dedicated clock inputs and routing. LatticeXP2 devices have two to four sysCLOCK PLLs, located in the four corners of the device. There are eight dedicated clock inputs, two on each side of the device. Figure 2-6 shows the primary clock sources.



Figure 2-6. Primary Clock Sources for XP2-17



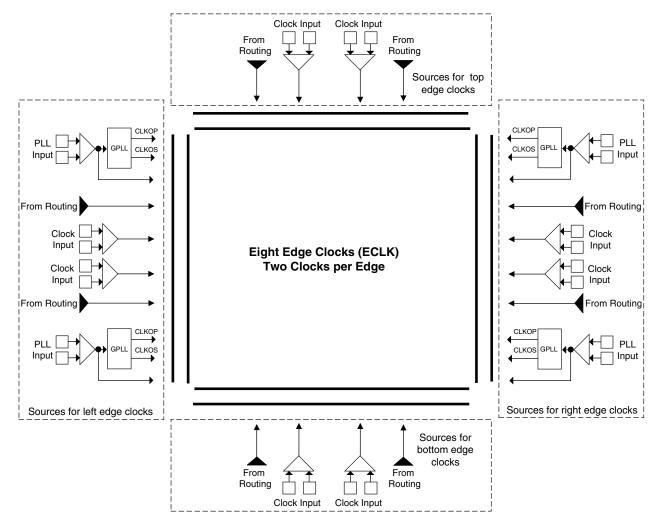
Note: This diagram shows sources for the XP2-17 device. Smaller LatticeXP2 devices have two GPLLs.



Edge Clock Sources

Edge clock resources can be driven from a variety of sources at the same edge. Edge clock resources can be driven from adjacent edge clock PIOs, primary clock PIOs, PLLs and clock dividers as shown in Figure 2-8.

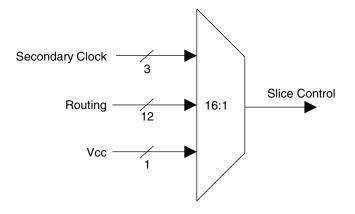
Figure 2-8. Edge Clock Sources



Note: This diagram shows sources for the XP2-17 device. Smaller LatticeXP2 devices have two GPLLs.



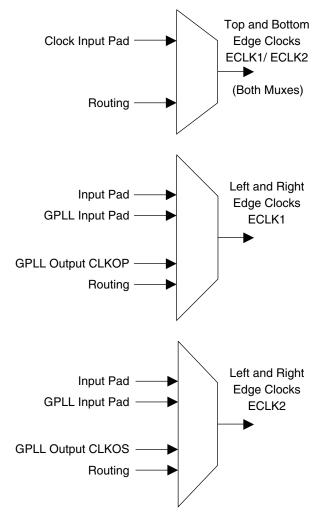
Figure 2-14. Slice0 through Slice2 Control Selection



Edge Clock Routing

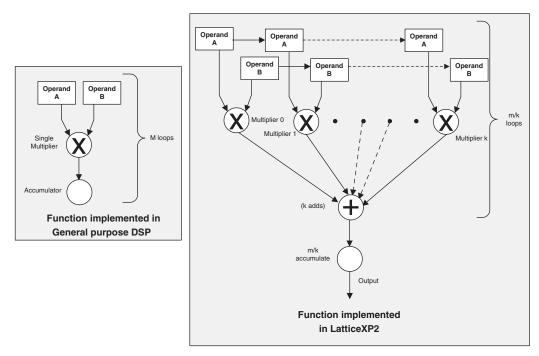
LatticeXP2 devices have eight high-speed edge clocks that are intended for use with the PIOs in the implementation of high-speed interfaces. Each device has two edge clocks per edge. Figure 2-15 shows the selection muxes for these clocks.

Figure 2-15. Edge Clock Mux Connections









sysDSP Block Capabilities

The sysDSP block in the LatticeXP2 family supports four functional elements in three 9, 18 and 36 data path widths. The user selects a function element for a DSP block and then selects the width and type (signed/unsigned) of its operands. The operands in the LatticeXP2 family sysDSP Blocks can be either signed or unsigned but not mixed within a function element. Similarly, the operand widths cannot be mixed within a block. DSP elements can be concatenated.

The resources in each sysDSP block can be configured to support the following four elements:

- MULT (Multiply)
- MAC (Multiply, Accumulate)
- MULTADDSUB (Multiply, Addition/Subtraction)
- MULTADDSUBSUM (Multiply, Addition/Subtraction, Accumulate)

The number of elements available in each block depends on the width selected from the three available options: x9, x18, and x36. A number of these elements are concatenated for highly parallel implementations of DSP functions. Table 2-6 shows the capabilities of the block.

Table 2-6. Maximum Number of Elements in a Block	
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Width of Multiply	x9	x18	x36
MULT	8	4	1
MAC	2	2	—
MULTADDSUB	4	2	—
MULTADDSUBSUM	2	1	—

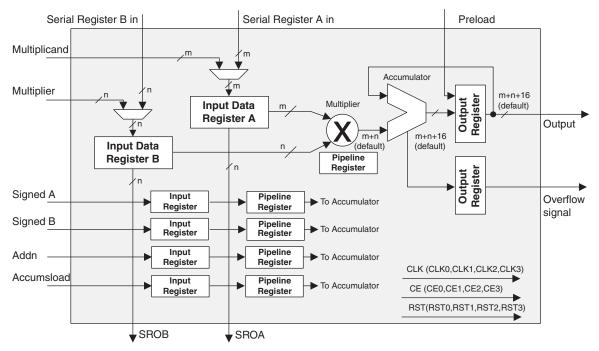
Some options are available in four elements. The input register in all the elements can be directly loaded or can be loaded as shift register from previous operand registers. By selecting 'dynamic operation' the following operations are possible:



MAC sysDSP Element

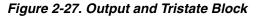
In this case, the two operands, A and B, are multiplied and the result is added with the previous accumulated value. This accumulated value is available at the output. The user can enable the input and pipeline registers but the output register is always enabled. The output register is used to store the accumulated value. The Accumulators in the DSP blocks in LatticeXP2 family can be initialized dynamically. A registered overflow signal is also available. The overflow conditions are provided later in this document. Figure 2-21 shows the MAC sysDSP element.

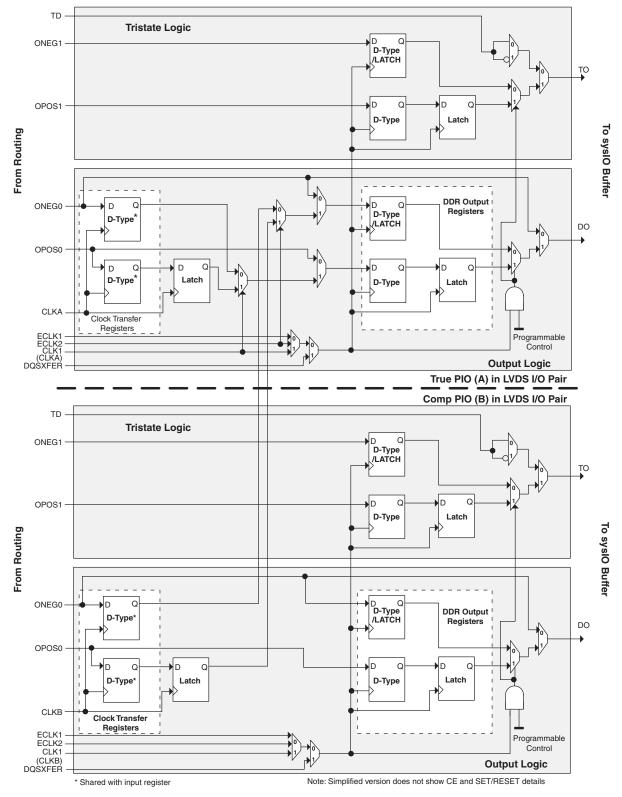
Figure 2-21. MAC sysDSP





shows the diagram using this gearbox function. For more information on this topic, see TN1138, <u>LatticeXP2 High</u> <u>Speed I/O Interface</u>.







LatticeXP2 Family Data Sheet DC and Switching Characteristics

September 2014

Data Sheet DS1009

Absolute Maximum Ratings^{1, 2, 3}

Supply Voltage V _{CC} 0.5 to 1.32V
Supply Voltage $V_{CCAUX} \dots \dots \dots 0.5$ to $3.75V$
Supply Voltage $V_{CCJ} \dots \dots \dots \dots 0.5$ to $3.75V$
Supply Voltage $V_{\mbox{\scriptsize CCPLL}}{}^4.\ldots\ldots$ -0.5 to 3.75V
Output Supply Voltage V_{CCIO} \ldots 0.5 to 3.75V
Input or I/O Tristate Voltage Applied $^5,\ldots\ldots$ -0.5 to 3.75V
Storage Temperature (Ambient) $\ldots \ldots$ -65 to 150°C
Junction Temperature Under Bias (Tj) +125°C

1. Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

2. Compliance with the Lattice <u>Thermal Management</u> document is required.

3. All voltages referenced to GND.

4. V_{CCPLL} only available on csBGA, PQFP and TQFP packages.

5. Overshoot and undershoot of -2V to (V_{IHMAX} + 2) volts is permitted for a duration of <20 ns.

Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Core Supply Voltage	1.14	1.26	V
V _{CCAUX} ^{4, 5}	Auxiliary Supply Voltage	3.135	3.465	V
V _{CCPLL} ¹	PLL Supply Voltage	3.135	3.465	V
V _{CCIO} ^{2, 3, 4}	I/O Driver Supply Voltage	1.14	3.465	V
V _{CCJ} ²	Supply Voltage for IEEE 1149.1 Test Access Port		3.465	V
t _{JCOM}	Junction Temperature, Commercial Operation	0	85	°C
t _{JIND}	Junction Temperature, Industrial Operation	-40	100	°C

1. V_{CCPLL} only available on csBGA, PQFP and TQFP packages.

If V_{CCIO} or V_{CCJ} is set to 1.2 V, they must be connected to the same power supply as V_{CC}. If V_{CCIO} or V_{CCJ} is set to 3.3V, they must be connected to the same power supply as V_{CCAUX}.

3. See recommended voltages by I/O standard in subsequent table.

4. To ensure proper I/O behavior, V_{CCIO} must be turned off at the same time or earlier than V_{CCAUX} .

5. In fpBGA and ftBGA packages, the PLLs are connected to, and powered from, the auxiliary power supply.

On-Chip Flash Memory Specifications

Symbol	Parameter	Max.	Units
	Flash Programming Cycles per t _{RETENTION} ¹	10,000	Cvcles
NPROGCYC	Flash Functional Programming Cycles	100,000	Oycles

1. The minimum data retention, t_{RETENTION}, is 20 years.

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Supply Current (Standby)^{1, 2, 3, 4}

Symbol	Parameter	Device	Typical⁵	Units
		XP2-5	14	mA
		XP2-8	18	mA
lcc	Core Power Supply Current	XP2-17	24	mA
		XP2-30	35	mA
		XP2-40	45	mA
		XP2-5	15	mA
		XP2-8	15	mA
CCAUX	Auxiliary Power Supply Current ⁶	XP2-17	15	mA
		XP2-30	16	mA
		XP2-40	16	mA
CCPLL	PLL Power Supply Current (per PLL)		0.1	mA
CCIO	Bank Power Supply Current (per bank)		2	mA
CCJ	V _{CCJ} Power Supply Current		0.25	mA

Over Recommended Operating Conditions

1. For further information on supply current, please see TN1139, Power Estimation and Management for LatticeXP2 Devices.

2. Assumes all outputs are tristated, all inputs are configured as LVCMOS and held at the V_{CCIO} or GND.

3. Frequency 0 MHz.

4. Pattern represents a "blank" configuration data file.

5. $T_J = 25^{\circ}C$, power supplies at nominal voltage.

6. In fpBGA and ftBGA packages the PLLs are connected to and powered from the auxiliary power supply. For these packages, the actual auxiliary supply current is the sum of I_{CCAUX} and I_{CCPLL}. For csBGA, PQFP and TQFP packages the PLLs are powered independent of the auxiliary power supply.



Initialization Supply Current^{1, 2, 3, 4, 5}

Over Recommended Operating Conditions

Symbol	Parameter	Device	Typical (25°C, Max. Supply)⁵	Units
		XP2-5	20	mA
		XP2-8	21	mA
I _{CC}	Core Power Supply Current	XP2-17	44	mA
		XP2-30	58	mA
		XP2-40	62	mA
		XP2-5	67	mA
		XP2-8	74	mA
I _{CCAUX}	Auxiliary Power Supply Current ⁷	XP2-17	112	mA
		XP2-30	124	mA
		XP2-40	130	mA
I _{CCPLL}	PLL Power Supply Current (per PLL)		1.8	mA
I _{CCIO}	Bank Power Supply Current (per Bank)		6.4	mA
I _{CCJ}	VCCJ Power Supply Current		1.2	mA

1. For further information on supply current, please see TN1139, Power Estimation and Management for LatticeXP2 Devices.

2. Assumes all outputs are tristated, all inputs are configured as LVCMOS and held at the V_{CCIO} or GND.

3. Frequency 0 MHz.

4. Does not include additional current from bypass or decoupling capacitor across the supply.

5. A specific configuration pattern is used that scales with the size of the device; consists of 75% PFU utilization, 50% EBR, and 25% I/O configuration.

6. $T_J = 25^{\circ}C$, power supplies at nominal voltage.

In fpBGA and ftBGA packages the PLLs are connected to and powered from the auxiliary power supply. For these packages, the actual
auxiliary supply current is the sum of I_{CCAUX} and I_{CCPLL}. For csBGA, PQFP and TQFP packages the PLLs are powered independent of the
auxiliary power supply.



sysIO Single-Ended DC Electrical Characteristics

Input/Output		V _{IL}	VII	1	V _{OL}	V _{OH}					
Standard	Min. (V)	Max. (V)	Min. (V)	Max. (V)	Max. (V)	Min. (V)	l _{OL} 1 (mA)	I _{OH} ¹ (mA)			
LVCMOS33	-0.3	0.8	2.0	3.6	0.4	V _{CCIO} - 0.4	20, 16, 12, 8, 4	-20, -16, -12, -8, -4			
					0.2	V _{CCIO} - 0.2	0.1	-0.1			
LVTTL33	-0.3	0.8	2.0	3.6	0.4	V _{CCIO} - 0.4	20, 16, 12, 8, 4	-20, -16, -12, -8, -4			
					0.2	V _{CCIO} - 0.2	0.1	-0.1			
LVCMOS25	-0.3	0.7	1.7	3.6	0.4	V _{CCIO} - 0.4	20, 16, 12, 8, 4	-20, -16, -12, -8, -4			
					0.2	V _{CCIO} - 0.2	0.1	-0.1			
LVCMOS18	-0.3	0.35 V _{CCIO}	0.65 V _{CCIO}	3.6	0.4	V _{CCIO} - 0.4	16, 12, 8, 4	-16, -12, -8, -4			
					0.2	V _{CCIO} - 0.2	0.1	-0.1			
LVCMOS15	-0.3	0.35 V _{CCIO}	0.65 V _{CCIO}	3.6	0.4	V _{CCIO} - 0.4	8, 4	-8, -4			
	-0.5	0.33 VCCIO	0.03 V CCIO	0.02 A CCIO	0.02 V CCIO	0.02 v CCIO	J.05 V _{CCIO} 3.0	0.2	V _{CCIO} - 0.2	0.1	-0.1
LVCMOS12	CMOS12 -0.3 0.35 V	0.35 V _{CC}	.35 V _{CC} 0.65 V _{CC}	3.6	0.4	V _{CCIO} - 0.4	6, 2	-6, -2			
LVONOSTZ	-0.5			5.0	0.2	V _{CCIO} - 0.2	0.1	-0.1			
PCI33	-0.3	0.3 V _{CCIO}	0.5 V _{CCIO}	3.6	0.1 V _{CCIO}	0.9 V _{CCIO}	1.5	-0.5			
SSTL33_I	-0.3	V _{REF} - 0.2	V _{REF} + 0.2	3.6	0.7	V _{CCIO} - 1.1	8	-8			
SSTL33_II	-0.3	V _{REF} - 0.2	V _{REF} + 0.2	3.6	0.5	V _{CCIO} - 0.9	16	-16			
SSTL25_I	-0.3	V _{BEE} - 0.18	V _{BFF} + 0.18	3.6	0.54	V _{CCIO} - 0.62	7.6	-7.6			
001220_1	0.0	VREF 0.10	VREF 1 0.10	0.0	0.01	*CCI0 0.02	12	-12			
SSTL25_II	-0.3	V _{RFF} - 0.18	V _{RFF} + 0.18	3.6	0.35	V _{CCIO} - 0.43	15.2	-15.2			
001220_11	0.0			0.0	0.00	VCCI0 0.10	20	-20			
SSTL18_I	-0.3	V _{REF} - 0.125	V _{REF} + 0.125	3.6	0.4	V _{CCIO} - 0.4	6.7	-6.7			
SSTL18_II	-0.3	Vpcc - 0 125	V _{REF} + 0.125	3.6	0.28	V _{CCIO} - 0.28	8	-8			
001210_11	0.0	VREF 0.120	VREF 1 0.120	0.0	0.20	*CCI0 0.20	11	-11			
HSTL15_I	-0.3	V _{REF} - 0.1	V _{RFF} + 0.1	3.6	0.4	V _{CCIO} - 0.4	4	-4			
							8	-8			
HSTL18_I	-0.3	V _{REF} - 0.1	V _{REF} + 0.1	3.6	0.4	V _{CCIO} - 0.4	8	-8			
							12	-12			
HSTL18_II	-0.3	V _{REF} - 0.1	V _{REF} + 0.1	3.6	0.4	V _{CCIO} - 0.4	16	-16			

Over Recommended Operating Conditions

 The average DC current drawn by I/Os between GND connections, or between the last GND in an I/O bank and the end of an I/O bank, as shown in the logic signal connections table shall not exceed n * 8mA, where n is the number of I/Os between bank GND connections or between the last GND in a bank and the end of a bank.



LatticeXP2 Internal Switching Characteristics¹ (Continued)

		-	7	-	6	-	5	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{HP_DSP}	Pipeline Register Hold Time	-0.787	_	-0.890	_	-0.994	—	ns
t _{SUO_DSP}	Output Register Setup Time	4.896	_	5.413	_	5.931	—	ns
t _{HO_DSP}	Output Register Hold Time	-1.439	_	-1.604	_	-1.770	—	ns
t _{COI_DSP} ³	Input Register Clock to Output Time	_	4.513	—	4.947	—	5.382	ns
t _{COP_DSP} ³	Pipeline Register Clock to Output Time	_	2.153	—	2.272	—	2.391	ns
t _{COO_DSP} ³	Output Register Clock to Output Time	_	0.569	—	0.600	—	0.631	ns
t _{SUADSUB}	AdSub Input Register Setup Time	-0.270	—	-0.298	_	-0.327	—	ns
t _{HADSUB}	AdSub Input Register Hold Time	0.306		0.338		0.371		ns

Over Recommended Operating Conditions

1. Internal parameters are characterized, but not tested on every device.

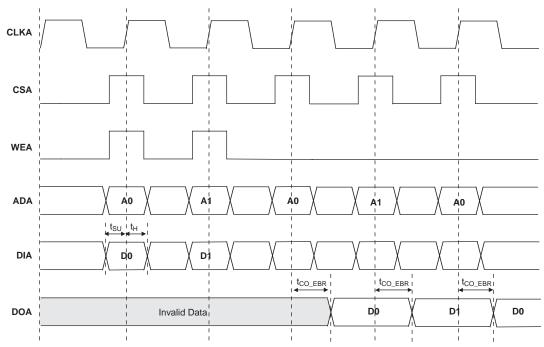
2. RST resets VCO and all counters in PLL.

3. These parameters include the Adder Subtractor block in the path.



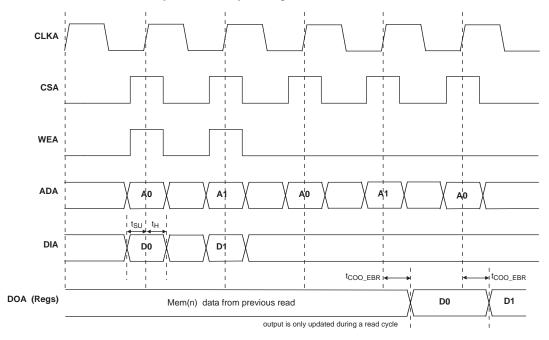
EBR Timing Diagrams





Note: Input data and address are registered at the positive edge of the clock and output data appears after the positive edge of the clock.

Figure 3-7. Read/Write Mode with Input and Output Registers



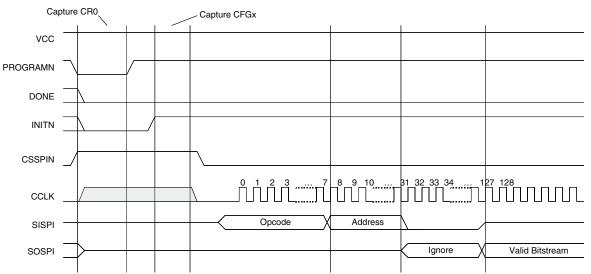


On-Chip Oscillator and Configuration Master Clock Characteristics

Parameter	Min.	Max.	Units
Master Clock Frequency	Selected value -30%	Selected value +30%	MHz
Duty Cycle	40	60	%

Over Recommended Operating Conditions

Figure 3-9. Master SPI Configuration Waveforms





Signal Descriptions (Cont.)

Signal Name	I/O	Description
TDO	0	Output pin. Test Data Out pin used to shift data out of a device using 1149.1.
VCCJ	-	Power supply pin for JTAG Test Access Port.
Configuration Pads (Used during sysC	ONFIG)	
CFG[1:0]	I	Mode pins used to specify configuration mode values latched on rising edge of INITN. During configuration, an internal pull-up is enabled.
INITN ¹	I/O	Open Drain pin. Indicates the FPGA is ready to be configured. During configuration, a pull-up is enabled.
PROGRAMN	Ι	Initiates configuration sequence when asserted low. This pin always has an active pull-up.
DONE	I/O	Open Drain pin. Indicates that the configuration sequence is complete, and the startup sequence is in progress.
CCLK	I/O	Configuration Clock for configuring an FPGA in sysCONFIG mode.
SISPI ²	I/O	Input data pin in slave SPI mode and Output data pin in Master SPI mode.
SOSPI ²	I/O	Output data pin in slave SPI mode and Input data pin in Master SPI mode.
CSSPIN ²	0	Chip select for external SPI Flash memory in Master SPI mode. This pin has a weak internal pull-up.
CSSPISN	Ι	Chip select in Slave SPI mode. This pin has a weak internal pull-up.
TOE	Ι	Test Output Enable tristates all I/O pins when driven low. This pin has a weak internal pull-up, but when not used an external pull-up to V_{CC} is recommended.

1. If not actively driven, the internal pull-up may not be sufficient. An external pull-up resistor of 4.7k to $10k\Omega$ is recommended.

2. When using the device in Master SPI mode, it must be mutually exclusive from JTAG operations (i.e. TCK tied to GND) or the JTAG TCK must be free-running when used in a system JTAG test environment. If Master SPI mode is used in conjunction with a JTAG download cable, the device power cycle is required after the cable is unplugged.



Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-30E-5FTN256C	1.2V	-5	Lead-Free ftBGA	256	COM	30
LFXP2-30E-6FTN256C	1.2V	-6	Lead-Free ftBGA	256	COM	30
LFXP2-30E-7FTN256C	1.2V	-7	Lead-Free ftBGA	256	COM	30
LFXP2-30E-5FN484C	1.2V	-5	Lead-Free fpBGA	484	COM	30
LFXP2-30E-6FN484C	1.2V	-6	Lead-Free fpBGA	484	COM	30
LFXP2-30E-7FN484C	1.2V	-7	Lead-Free fpBGA	484	COM	30
LFXP2-30E-5FN672C	1.2V	-5	Lead-Free fpBGA	672	COM	30
LFXP2-30E-6FN672C	1.2V	-6	Lead-Free fpBGA	672	COM	30
LFXP2-30E-7FN672C	1.2V	-7	Lead-Free fpBGA	672	COM	30

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-40E-5FN484C	1.2V	-5	Lead-Free fpBGA	484	COM	40
LFXP2-40E-6FN484C	1.2V	-6	Lead-Free fpBGA	484	COM	40
LFXP2-40E-7FN484C	1.2V	-7	Lead-Free fpBGA	484	COM	40
LFXP2-40E-5FN672C	1.2V	-5	Lead-Free fpBGA	672	COM	40
LFXP2-40E-6FN672C	1.2V	-6	Lead-Free fpBGA	672	COM	40
LFXP2-40E-7FN672C	1.2V	-7	Lead-Free fpBGA	672	COM	40

Industrial

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-5E-5MN132I	1.2V	-5	Lead-Free csBGA	132	IND	5
LFXP2-5E-6MN132I	1.2V	-6	Lead-Free csBGA	132	IND	5
LFXP2-5E-5TN144I	1.2V	-5	Lead-Free TQFP	144	IND	5
LFXP2-5E-6TN144I	1.2V	-6	Lead-Free TQFP	144	IND	5
LFXP2-5E-5QN208I	1.2V	-5	Lead-Free PQFP	208	IND	5
LFXP2-5E-6QN208I	1.2V	-6	Lead-Free PQFP	208	IND	5
LFXP2-5E-5FTN256I	1.2V	-5	Lead-Free ftBGA	256	IND	5
LFXP2-5E-6FTN256I	1.2V	-6	Lead-Free ftBGA	256	IND	5

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-8E-5MN132I	1.2V	-5	Lead-Free csBGA	132	IND	8
LFXP2-8E-6MN132I	1.2V	-6	Lead-Free csBGA	132	IND	8
LFXP2-8E-5TN144I	1.2V	-5	Lead-Free TQFP	144	IND	8
LFXP2-8E-6TN144I	1.2V	-6	Lead-Free TQFP	144	IND	8
LFXP2-8E-5QN208I	1.2V	-5	Lead-Free PQFP	208	IND	8
LFXP2-8E-6QN208I	1.2V	-6	Lead-Free PQFP	208	IND	8
LFXP2-8E-5FTN256I	1.2V	-5	Lead-Free ftBGA	256	IND	8
LFXP2-8E-6FTN256I	1.2V	-6	Lead-Free ftBGA	256	IND	8



Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-40E-5F484C	1.2V	-5	fpBGA	484	COM	40
LFXP2-40E-6F484C	1.2V	-6	fpBGA	484	COM	40
LFXP2-40E-7F484C	1.2V	-7	fpBGA	484	COM	40
LFXP2-40E-5F672C	1.2V	-5	fpBGA	672	COM	40
LFXP2-40E-6F672C	1.2V	-6	fpBGA	672	COM	40
LFXP2-40E-7F672C	1.2V	-7	fpBGA	672	COM	40

Industrial

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-5E-5M132I	1.2V	-5	csBGA	132	IND	5
LFXP2-5E-6M132I	1.2V	-6	csBGA	132	IND	5
LFXP2-5E-6FT256I	1.2V	-6	ftBGA	256	IND	5

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-8E-5M132I	1.2V	-5	csBGA	132	IND	8
LFXP2-8E-6M132I	1.2V	-6	csBGA	132	IND	8
LFXP2-5E-5FT256I	1.2V	-5	ftBGA	256	IND	5
LFXP2-8E-5FT256I	1.2V	-5	ftBGA	256	IND	8
LFXP2-8E-6FT256I	1.2V	-6	ftBGA	256	IND	8

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-17E-5FT256I	1.2V	-5	ftBGA	256	IND	17
LFXP2-17E-6FT256I	1.2V	-6	ftBGA	256	IND	17
LFXP2-17E-5F484I	1.2V	-5	fpBGA	484	IND	17
LFXP2-17E-6F484I	1.2V	-6	fpBGA	484	IND	17

Part Number	Voltage	Grade	Package	Pins	Temp.	LUTs (k)
LFXP2-30E-5FT256I	1.2V	-5	ftBGA	256	IND	30
LFXP2-30E-6FT256I	1.2V	-6	ftBGA	256	IND	30
LFXP2-30E-5F484I	1.2V	-5	fpBGA	484	IND	30
LFXP2-30E-6F484I	1.2V	-6	fpBGA	484	IND	30
LFXP2-30E-5F672I	1.2V	-5	fpBGA	672	IND	30
LFXP2-30E-6F672I	1.2V	-6	fpBGA	672	IND	30



LatticeXP2 Family Data Sheet Revision History

September 2014

Data Sheet DS1009

Revision History

	Version	Section	Change Summary
May 2007	01.1		Initial release.
September 2007	01.2	DC and Switching Characteristics	Added JTAG Port Timing Waveforms diagram.
			Updated sysCLOCK PLL Timing table.
		Pinout Information	Added Thermal Management text section.
February 2008	01.3	Architecture	Added LVCMOS33D to Supported Output Standards table.
			Clarified: "This Flash can be programmed through either the JTAG or Slave SPI ports of the device. The SRAM configuration space can also be infinitely reconfigured through the JTAG and Master SPI ports."
			Added External Slave SPI Port to Serial TAG Memory section. Updated Serial TAG Memory diagram.
		DC and Switching Characteristics	Updated Flash Programming Specifications table.
			Added "8W" specification to Hot Socketing Specifications table.
			Updated Timing Tables
			Clarifications for IIH in DC Electrical Characteristics table.
			Added LVCMOS33D section
			Updated DOA and DOA (Regs) to EBR Timing diagrams.
			Removed Master Clock Frequency and Duty Cycle sections from the LatticeXP2 sysCONFIG Port Timing Specifications table. These are listed on the On-chip Oscillator and Configuration Master Clock Characteristics table.
			Changed CSSPIN to CSSPISN in description of $t_{SCS},t_{SCSS},$ and t_{SCSH} parameters. Removed t_{SOE} parameter.
			Clarified On-chip Oscillator documentation
			Added Switching Test Conditions
		Pinout Information	Added "True LVDS Pairs Bonding Out per Bank," "DDR Banks Bonding Out per I/O Bank," and "PCI capable I/Os Bonding Out per Bank" to Pin Information Summary in place of previous blank table "PCI and DDR Capabilities of the Device-Package Combinations"
			Removed pinout listing. This information is available on the LatticeXP2 product web pages
		Ordering Information	Added XP2-17 "8W" and all other family OPNs.
April 2008	01.4	DC and Switching	Updated Absolute Maximum Ratings footnotes.
		Characteristics	Updated Recommended Operating Conditions Table footnotes.
			Updated Supply Current (Standby) Table
			Updated Initialization Supply Current Table
			Updated Programming and Erase Flash Supply Current Table
			Updated Register to Register Performance Table
			Updated LatticeXP2 External Switching Characteristics Table
			Updated LatticeXP2 Internal Switching Characteristics Table
			Updated sysCLOCK PLL Timing Table

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